

Advance Technical Information

Polar[™] Power MOSFET

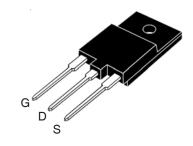
IXTQ69N30PM

 $V_{DSS} = 300V$ $I_{D25} = 25A$ $R_{DC(27)} \le 49m\Omega$

N-Channel Enhancement Mode Avalanche Rated Fast Intrinsic Diode



OVERMOLDED (IXTQ...M) OUTLINE



G = Gate D = DrainS = Source

Symbol	Test Conditions	Maximum Ra	Maximum Ratings		
V _{DSS}	$T_J = 25^{\circ}\text{C to } 150^{\circ}\text{C}$ $T_J = 25^{\circ}\text{C to } 150^{\circ}\text{C}, R_{GS} = 1 \text{ M}\Omega$	300 300	V		
V _{DGR}	1 _J = 23 0 to 130 0, 11 _{GS} = 1 1VIS2	300	v		
V _{GSS}	Continuous	± 20	V		
V _{GSM}	Transient	± 30	V		
I _{D25}	T _c = 25°C	25	Α		
I _{DM}	$T_{C} = 25^{\circ}C$, Pulse Width Limited by T_{JM}	200	Α		
IA	T _C = 25°C	69	А		
I _A E _{AS}	$T_{C}^{-} = 25^{\circ}C$	1.5	J		
dv/dt	$I_{_{S}} \le I_{_{DM}}, \ V_{_{DD}} \le V_{_{DSS}}, T_{_{J}} = 150^{\circ}C$	15	V/ns		
P_{D}	T _C = 25°C	90	W		
T _J		- 55 +150	°C		
T _{JM}		150	°C		
T _{stg}		- 55 +150	°C		
T,	1.6 mm (0.062 in.) from Case for 10 s	300	°C		
T _{SOLD}	Plastic Body for 10 s	260	°C		
M _d	Mounting Torque	1.13/10	Nm/lb.in.		
Weight		2.5	g		

Features

- Plastic Overmolded Tab for Electrical Isolation
- Avalanche Rated
- Fast Intrinsic Diode
- Low Package Inductance

- High Power Density
- Easy to Mount

Advantages

Space Savings

Applications

- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- Laser Drivers
- AC and DC Motor Drives
- Robotics and Servo Controls

		Chara Min.	racteristic Values Typ. Max.		
BV _{DSS}	$V_{GS} = 0V, I_D = 250\mu A$	300			V
V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250\mu A$	2.5		5.0	V
I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100	nΑ
I _{DSS}	$V_{DS} = V_{DSS}, V_{GS} = 0V$ $T_{J} = 125^{\circ}C$			5 100	μ Α μ Α
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 34.5A, Note 1$			49 r	nΩ



Symbol Test Conditions Char		Chara	cteristic Values		
$(T_{J} = 25^{\circ}C, U)$	Jnless Otherwise Specified)	Min.	Тур.	Max.	
g _{fs}	$V_{DS} = 10V, I_{D} = 34.5A, Note 1$	27	45	S	
C _{iss}			4960	pF	
C _{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		760	pF	
C _{rss})		190	pF	
t _{d(on)}	Decistive Switching Times		25	ns	
t, (Resistive Switching Times		25	ns	
t _{d(off)}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 34.5A$		75	ns	
t _r	$R_{\rm G} = 4\Omega$ (External)		27	ns	
$\mathbf{Q}_{g(on)}$			156	nC	
Q _{gs}	$V_{GS} = 10V, V_{DS} = 0.5 \bullet V_{DSS}, I_{D} = 34.5A$		32	nC	
Q _{gd}	э _е 7		79	nC	
R _{thJC}				1.38 °C/W	

SYM	INCHES		MILLIMETERS		
	MIN	MAX	MIN	MAX	
Α	.213	.228	5.40	5.80	
A1	.122	.138	3.10	3.50	
A2 A3	.114	.130	2.90	3.30	
А3	.075	.091	1.90	2.30	
Ь	.026	.037	0.65	0.95	
b2	.075	.091	1,90	2,30	
U	.031	.043	0.80	1.10	
D	.957	.972	24.30	24.70	
D1	.051	.067	1.30	1.70	
D2	.071	.087	1.80	2.20	
Ε	.606	.622	15.40	15.80	
E1	.154	.169	3.90	4.30	
е	.215 BSC		5,45 BSC		
L	.748	.768	19.00	19.50	
L1	.169	.185	4.30	4.70	
øΡ	.134	.150	3.40	3.80	
R	.209	.224	5.30	5.70	
S	.169	.185	4.30	4.70	

Source-Drain Diode

		Charact Min.	Characteristic Values Min.		
I _s	$V_{GS} = 0V$			69	Α
I _{SM}	Repetitive, Pulse Width Limited by $T_{_{\rm JM}}$			270	Α
V _{SD}	$I_F = I_S$, $V_{GS} = 0V$, Note 1			1.5	V
$\left\{egin{array}{c} \mathbf{t}_{rr} \ \mathbf{Q}_{RM} \end{array} ight\}$	$I_F = 25A$, -di/dt = 100A/ μ s $V_R = 100V$, $V_{GS} = 0V$		250 3.0		ns µC

Note 1. Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2$ %.

ADVANCE TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.



Fig. 1. Output Characteristics @ T_J = 25°C

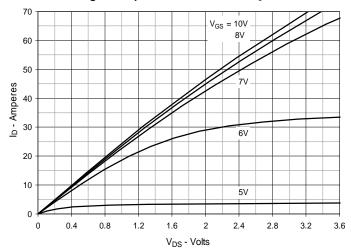


Fig. 2. Extended Output Characteristics @ T_J = 25°C

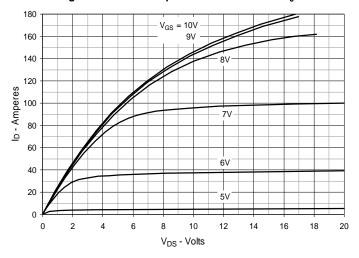


Fig. 3. Output Characteristics @ T_J = 125°C

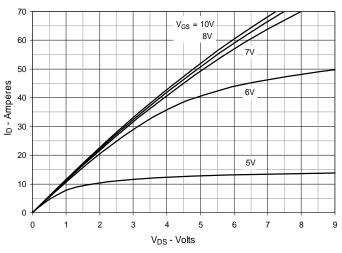


Fig. 4. $R_{DS(on)}$ Normalized to I_D = 34.5A Value vs. Junction Temperature

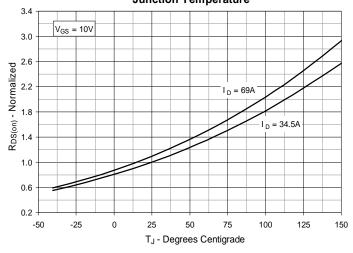


Fig. 5. R_{DS(on)} Normalized to I_D = 34.5A Value vs. Drain Current

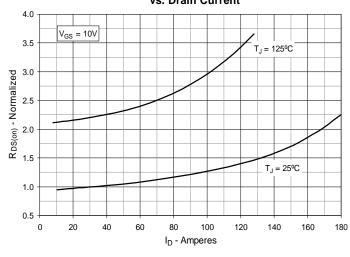
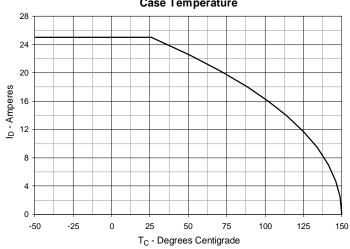
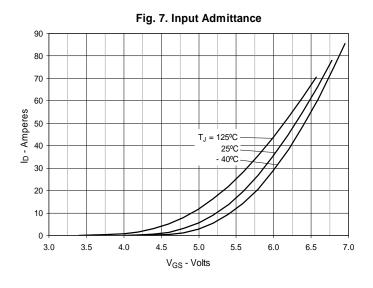


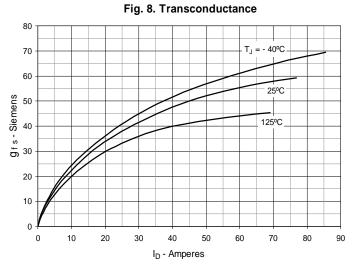
Fig. 6. Maximum Drain Current vs.

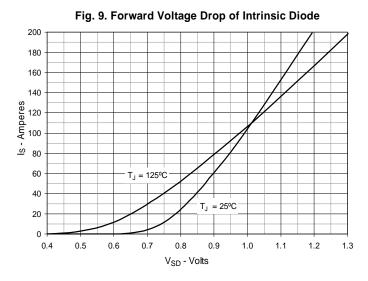
Case Temperature

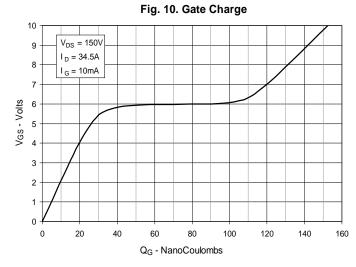


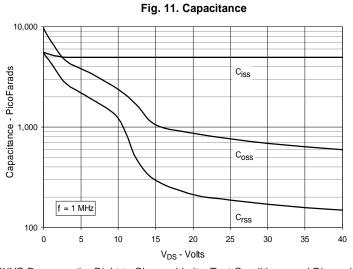


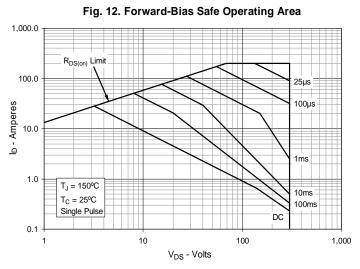












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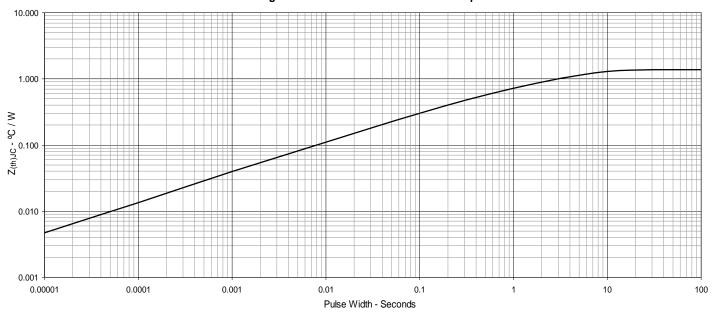


Fig. 13. Maximum Transient Thermal Impedance

